

# Group meeting : Low-field dipolar interaction between NV centers in diamond

March 24, 2022

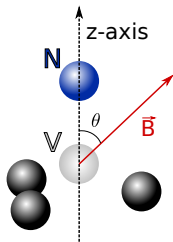
# Outline

- 1 (Quick) Reminder on NV center
- 2 Dipolar interaction and spin lifetime
- 3 The fluctuator model
- 4 The reasons behind the dip in zero-field
- 5 Low-field Magnetometry

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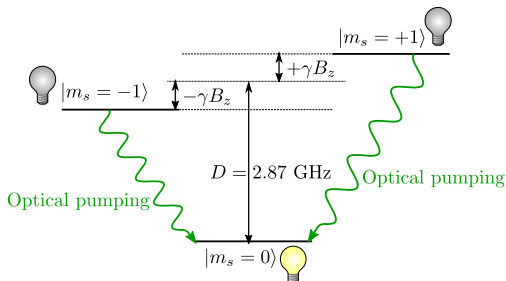
# NV<sup>-</sup> spin in the fundamental electronic state



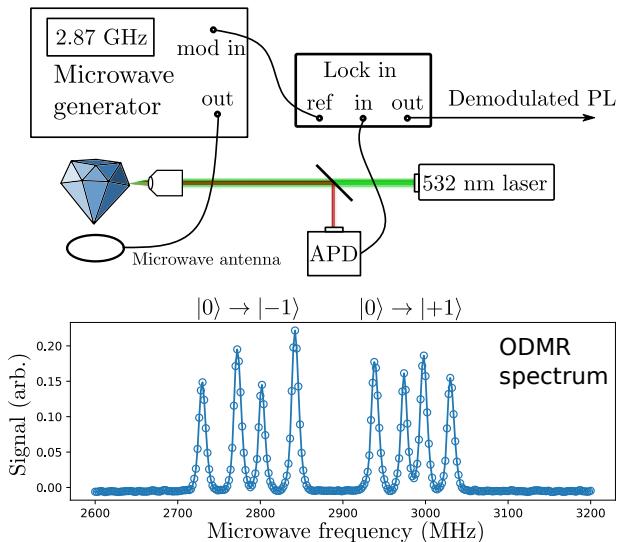
$$\mathcal{H} = D\hat{S}_z^2 + \gamma_e \hat{\mathbf{S}} \cdot \mathbf{B}$$

$\mathbf{z}$  of  $\hat{S}_z$  defined by  
the crystalline axis

- $|0\rangle$  state brighter than  $|\pm 1\rangle$  state by  $\sim 30\%$
- polarization in  $|0\rangle$  state of  $\sim 80\%$   
(equivalent to  $\sim 65\ \mu\text{K}$ )



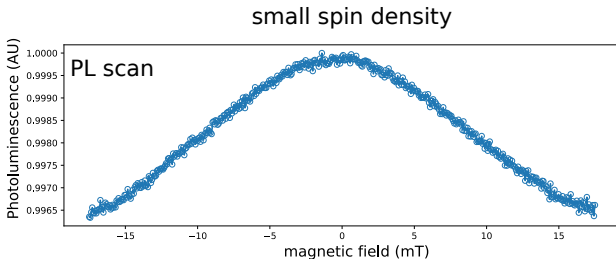
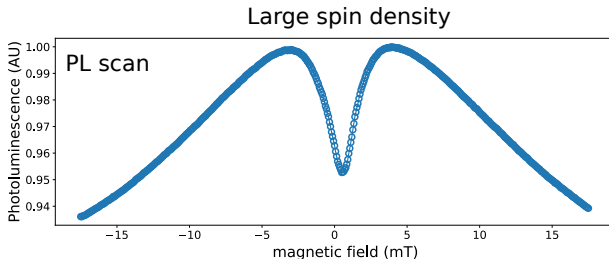
# Principle of CW ODMR



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# Today's goal : understand the PL dip in zero-field

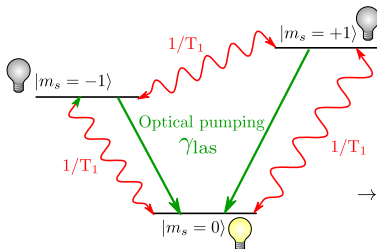
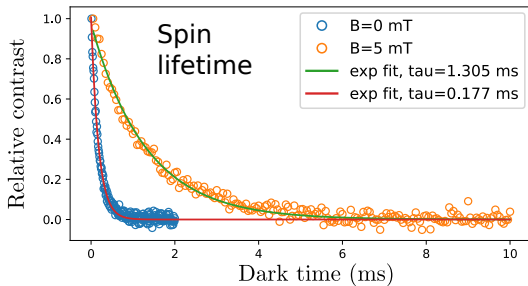


# Why does it matter ?

- The concentration of  $\text{NV}^-$  centers (while maintaining good spectral properties) is increasing.
- Magnetometry in low field is already hard with standard techniques.
- The dip itself can be used to perform low-field, microwave-less magnetometry.



# Link between the PL and the spin T1



$$PL \propto \rho_{00}$$

$$\rho_{00} = \frac{\gamma_{\text{las}}}{\gamma_{\text{las}} + 3\gamma_1} \quad (\gamma_1 = 1/T_1)$$

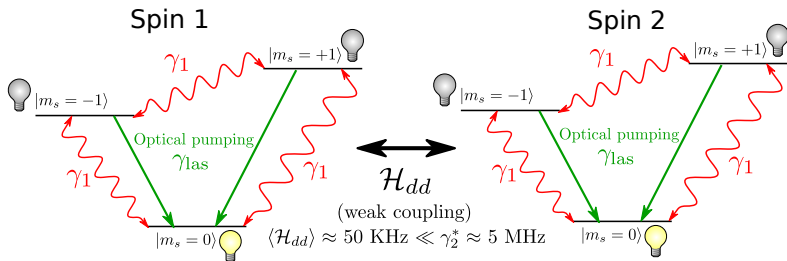
→ The PL decreases when  $\gamma_1$  increases

# Spin relaxation amplified by dipolar coupling

See animation

# Dipolar interaction should not modify the total spin polarization...

## Homogeneous case

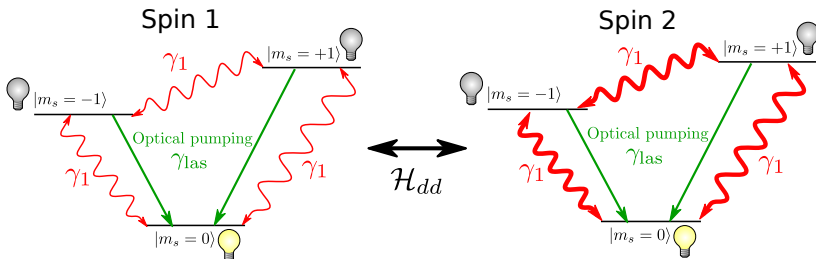


Flip-flop processes ( $|-1; 0\rangle \rightarrow |0; -1\rangle$ ) preserve the spin population in  $|0\rangle$

→ Dipolar coupling does not modify the ensemble spin lifetime

...except with inhomogeneities

### Inhomogeneous case : $\gamma_1 < \gamma'_1$



Spin 2 is less polarized than spin 1 ( $\rho_{00}^2 < \rho_{00}^1$ )

→ The process  $|0; -1\rangle \rightarrow |-1; 0\rangle$  is more likely than  $|-1; 0\rangle \rightarrow |0; -1\rangle$

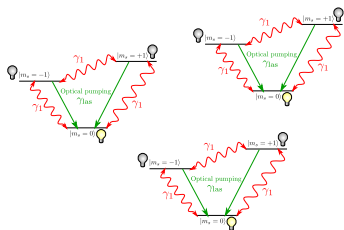
→ The combined action of the dipolar coupling and the inhomogeneous relaxation rates can reduce the ensemble spin lifetime

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# Theoretical frame : the fluctuator model

## "Normal" NVs

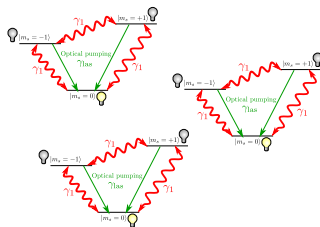


$$\gamma_1 \ll \gamma_{\text{las}}$$

$$\hat{\rho} \approx \begin{pmatrix} 0.1 & 0 & 0 \\ 0 & 0.8 & 0 \\ 0 & 0 & 0.1 \end{pmatrix}$$

$$\mathcal{H}_{dd} \longleftrightarrow$$

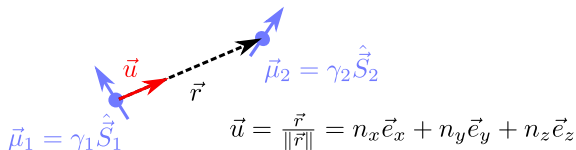
## Fluctuator NVs



$$\gamma_1 \gg \gamma_{\text{las}}$$

$$\hat{\rho} \approx \begin{pmatrix} 0.33 & 0 & 0 \\ 0 & 0.33 & 0 \\ 0 & 0 & 0.33 \end{pmatrix}$$

# The dipole-dipole Hamiltonian



$$\mathcal{H}_{dd} = -\frac{\mu_0 \gamma_1 \gamma_2 \hbar^2}{4\pi r^3} [3(\hat{S}_1 \cdot \vec{u})(\hat{S}_2 \cdot \vec{u}) - \hat{S}_1 \cdot \hat{S}_2]$$

Every matrix element  $\langle i; \alpha | \mathcal{H}_{dd} | j; \beta \rangle$  can be written as  $\xi(\|\vec{r}\|) \eta(\vec{u})$

Example :  $\langle 0; -1 | \mathcal{H}_{dd} | -1; 0 \rangle$  is the matrix element for a flip-flop process

## $\mathcal{H}_{dd}$ for two aligned spin

In the magnetic basis  $(|-1\rangle, |0\rangle, |+1\rangle) \otimes (|-1\rangle, |0\rangle, |+1\rangle)$  :

$$\mathcal{H}_{dd} \propto \left( \frac{3}{2}(n_x^2 + n_y^2) - 1 \right) [|0; +1\rangle\langle +1; 0| + |-1; 0\rangle\langle 0; -1| + h.c.] \quad (1)$$

$$+ \frac{3}{2}(n_x^2 - n_y^2 + i2n_x n_y) [|0; +1\rangle\langle -1; 0| + |+1; 0\rangle\langle 0; -1|] \quad (2)$$

$$+ \frac{3}{2}(n_x^2 - n_y^2 - i2n_x n_y) [|0; -1\rangle\langle +1; 0| + |-1; 0\rangle\langle 0; +1|] \quad (3)$$

$$+ (3n_z^2 - 1)\hat{S}_z^1 \hat{S}_z^2 \quad (4)$$

$$+ \mathcal{H}_{\text{other}} \quad (5)$$

Example :  $\eta_{\text{flip-flop}} = \frac{3}{2}(n_x^2 + n_y^2) - 1$



# The fluctuator model : calculation steps

- Decay rate induced by a single fluctuator on a single NV :

$$\Gamma_{ij} = \sum_{\alpha, \beta} |\langle i, \alpha | \mathcal{H}_{dd} | j, \beta \rangle|^2 \frac{\gamma_f}{(\omega_{ij} - \omega_{\beta\alpha})^2 + \gamma_f^2}$$

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- Each NV will see a total decay rate

$$\gamma = \sum_{\text{fluct}} \Gamma_{ij}(\vec{r})$$

# The fluctuator model : calculation steps

- We can compute the distribution of these individual decay rates  $\gamma$  :

$$\begin{aligned}\rho(\gamma) &= \int \{d_{\text{fluct}}\} \delta\left(\gamma - \sum_{\text{fluct}} \Gamma_{ij}(\vec{r})\right) \\ &= \frac{e^{-1/(4\gamma T)}}{\sqrt{4\pi\gamma^3 T}}\end{aligned}$$

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- The measured lifetime will be averaged over all the NVs :

$$PL(t) = \int e^{-\gamma t} \rho(\gamma) d\gamma = e^{-\sqrt{t/T}}$$

# The fluctuator model : calculation steps

Where :

$$T \equiv \left( \frac{4\pi n_f J_0 \bar{\eta}}{3} \right)^2 \frac{\pi}{\gamma_f}$$

With :

- $n_f$  is the fluctuator density
- $\gamma_f$  is the fluctuator decay rate

and :

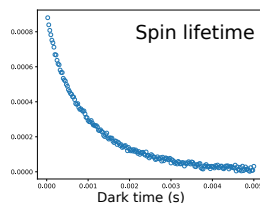
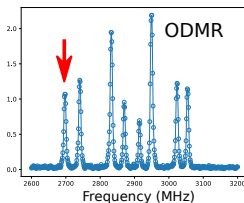
$$\bar{\eta} \equiv \frac{1}{4} \sum_{\text{classes}} \frac{\gamma_f^2}{(\omega_{\text{NV}} - \omega_{\text{fluct}})^2 + \gamma_f^2} \int_{\theta, \phi} |\eta(\theta, \phi)| d\Omega$$

# Examples

$$\bar{\eta} = \frac{1}{4} \int_{\theta, \phi} |\eta(\theta, \phi)| d\Omega$$

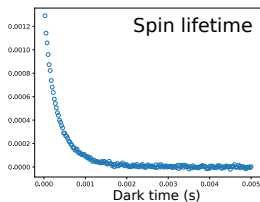
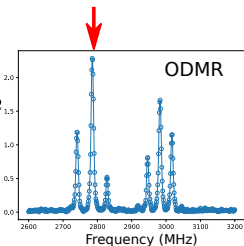
$$= \frac{1}{4} \times 0.3849$$

$$T \propto \frac{1}{\bar{\eta}^2}$$

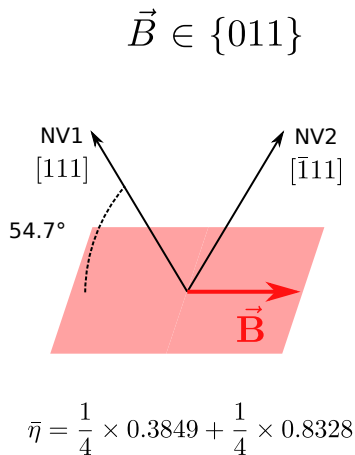
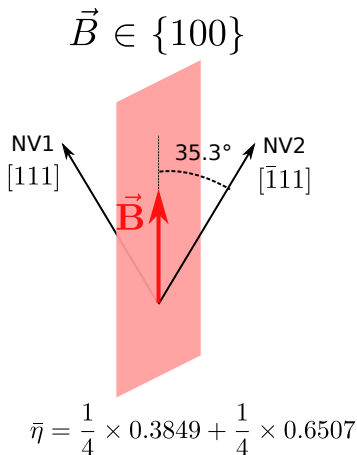


$$\bar{\eta} = \frac{1}{4} \int_{\theta, \phi} |\eta(\theta, \phi)| d\Omega + \frac{1}{4} \int_{\theta, \phi} |\eta'(\theta, \phi)| d\Omega$$

$$= \frac{1}{4} * 0.3849 + \frac{1}{4} * 0.8328$$



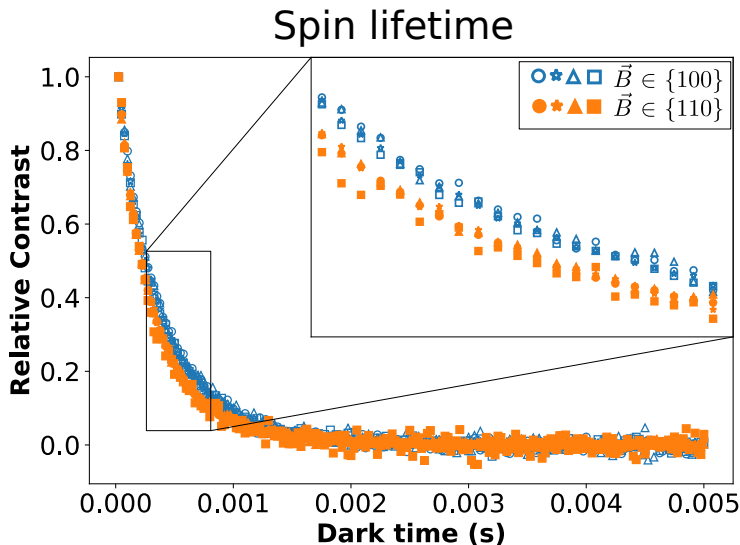
# Non-trivial prediction of the model



$$\bar{\eta}^{100} < \bar{\eta}^{011}$$

→ We should observe  $T_1^{100} > T_1^{011}$

# Non-trivial prediction of the model

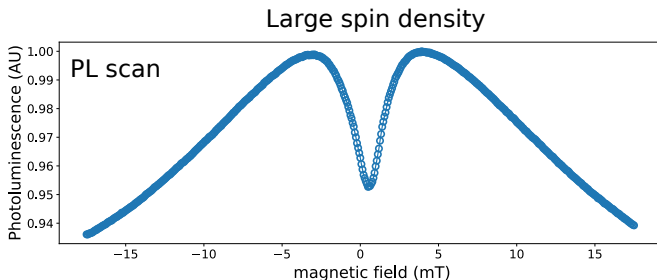




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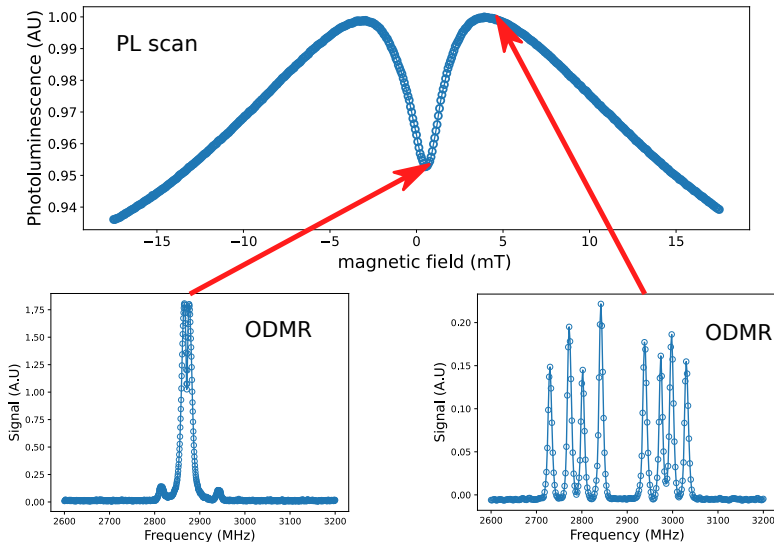
# The reasons behind the dip in zero-field



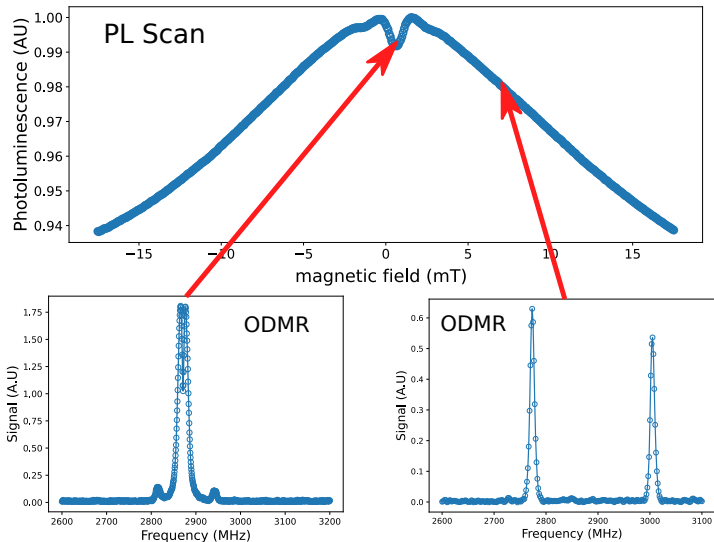
There are 3 parts, all linked to dipolar coupling :

- 1 The lift of the degeneracies between the four classes
- 2 The change of the eigenstates in the avoided crossing region
- 3 The double-flip terms in the dipolar Hamiltonian

# 1. The lift of the degeneracies



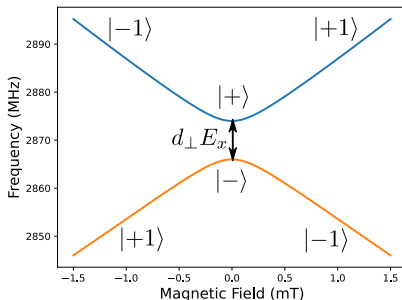
But it is not the only reason



## 2. The change in eigenstates of $\mathcal{H}_0$

$$\mathcal{H}_0 = \begin{pmatrix} D - \gamma_e B_z & \gamma_e B_x & d_{\perp} E_x \\ \gamma_e B_x & 0 & \gamma_e B_x \\ d_{\perp} E_x & \gamma_e B_x & D + \gamma_e B_z \end{pmatrix}$$

$$D = 2870 \text{ MHz} \quad \begin{array}{l} \gamma_e B_x = 0 - 500 \text{ MHz} \\ \gamma_e B_z = 0 - 500 \text{ MHz} \end{array} \quad d_{\perp} E_x \approx 5 \text{ MHz}$$



$$| + \rangle = \frac{| +1 \rangle + | -1 \rangle}{\sqrt{2}}$$

$$| - \rangle = \frac{| +1 \rangle - | -1 \rangle}{\sqrt{2}}$$

# Dipolar Hamiltonian in the coupled basis

In the coupled basis  $(|-\rangle, |0\rangle, |+\rangle) \otimes (|-\rangle, |0\rangle, |+\rangle)$  :

$$\mathcal{H}_{dd} = (3n_x^2 - 1) [|0; +\rangle\langle +; 0| + h.c.] \quad (1)$$

$$+ (3n_y^2 - 1) [|0; -\rangle\langle -; 0| + h.c.] \quad (2)$$

$$+ i3n_x n_y [|0; +\rangle\langle -; 0| + |+\rangle\langle 0; -| + h.c.] \quad (3)$$

$$+ (3n_z^2 - 1) [|+; -\rangle\langle -; +| + h.c.] \quad (4)$$

$$+ \mathcal{H}_{\text{other}} \quad (5)$$

$$\eta_{\text{flip-flop}} = 3n_x^2 - 1 \text{ or } 3n_y^2 - 1 \neq \frac{3}{2}(n_x^2 + n_y^2) - 1$$

$$\rightarrow \bar{\eta}_{\text{flip-flop}}(|\pm 1\rangle) = 0.3849 < \bar{\eta}_{\text{flip-flop}}(|\pm\rangle) = 0.7698$$

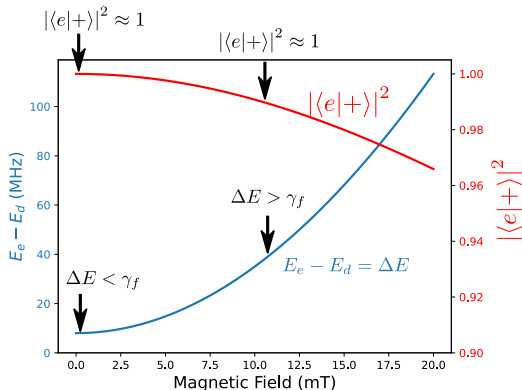
# $\mathcal{H}_0$ under pure transverse field

Eigen states of  $\mathcal{H}_0$  when  $\vec{B} \parallel \vec{e}_x$  :

- $|e\rangle \approx |+\rangle$
- $|d\rangle = |-\rangle$
- $|g\rangle \approx |0\rangle$

$$|+\rangle = \frac{|+1\rangle + |-1\rangle}{\sqrt{2}}$$

$$|-\rangle = \frac{|+1\rangle - |-1\rangle}{\sqrt{2}}$$

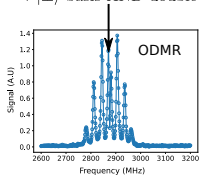


$$\bar{\eta} \propto \frac{\gamma_f^2}{(\Delta E)^2 + \gamma_f^2}$$

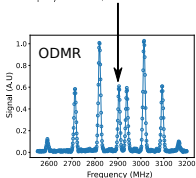
$$\gamma_f \approx 15 \text{ MHz}$$

# Experimental results with transverse field

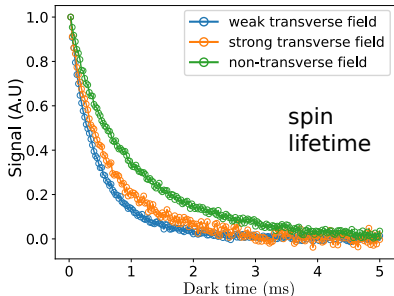
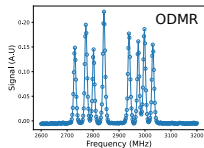
Weak transverse field :  
→  $|\pm\rangle$  basis AND double flips



Strong transverse field :  
→  $|\pm\rangle$  basis, no double flips



Non-transverse field :  
→  $|\pm 1\rangle$  basis, no double flips

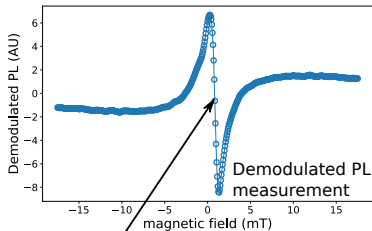
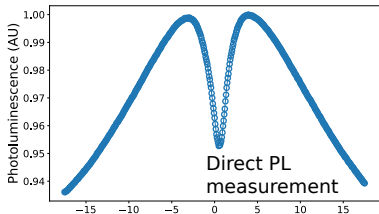




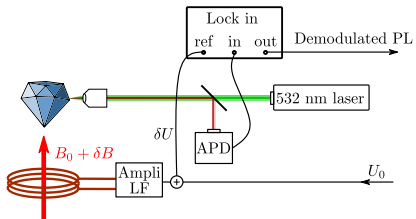
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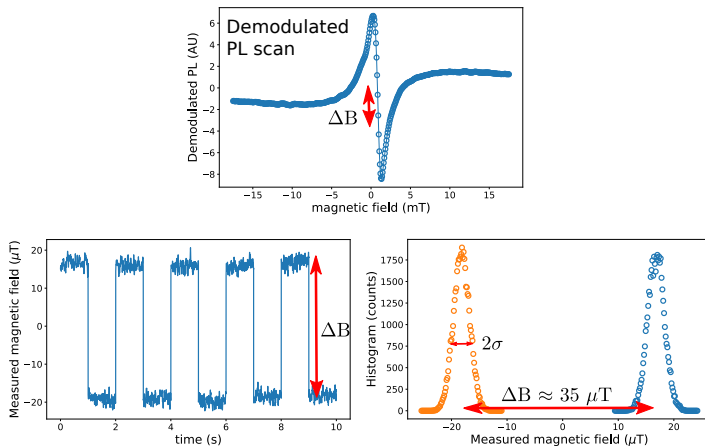
## Low field magnetometry experimental setup



Highest sensitivity  
region



# Magnetometry protocol



$$\text{Sensitivity} = \sigma \sqrt{\tau_{\text{meas}}} \\ \approx 100 \text{ nT}/\sqrt{\text{Hz}}$$

## Importance of the various effects on the sensitivity

